

HIGH EFFICIENCY SWITCHED MODE RECTIFIER

MAIN PRODUCT CHARACTERISTICS

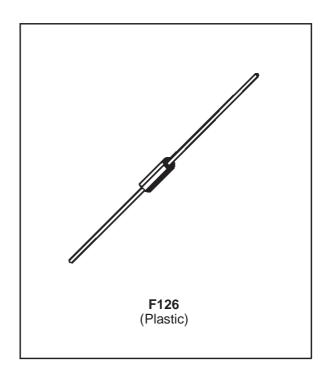
I _{F(AV)}	2A
V _{RRM}	200V
V _F (max)	0.8V

FEATURES AND BENEFITS

- VERY LOW CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD AND REVERSE RECOVERY TIMES
- HIGH SURGE CURRENT



Low voltage drop rectifiers suited for Switched Mode Power Supplies and for switching mode base drive and transistor circuit.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	200	V	
V _{RSM}	Non repetitive peak reverse voltage		220	V
I _{FRM}	Repetive peak forward current	70	Α	
IF (AV)	Average forward current *	ward current * $T_a = 75^{\circ}C$ $\delta = 0.5$		А
IFSM	Surge non repetitive forward current $t_p = 10 \text{ms}$ Sinusoidal		70	А
P _{tot}	Power dissipation *	T _a = 75°C	1.85	W
T _{stg} T _j	Storage temperature range Maximum junction temperature	- 40 to + 150 150	°C	
TL	Maximum lead temperature for soldering 4mm from case	230	ů	

^{*} On infinite heatsink with 10mm lead length

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STSR220

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth (j - a)	Junction to ambient thermal resistance *	40	°C/W

^{*} On infinite heatsink with 10mm lead lengh.

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _R	Reverse leakage current	V _R = V _{RRM}	T _j = 25°C			10	μΑ
			T _j = 100℃			0.5	mA
VF	Forward voltage	I _F = 2A	T _j = 25°C			1	V
	drop	I _F = 2A	T _j = 100℃			0.8	

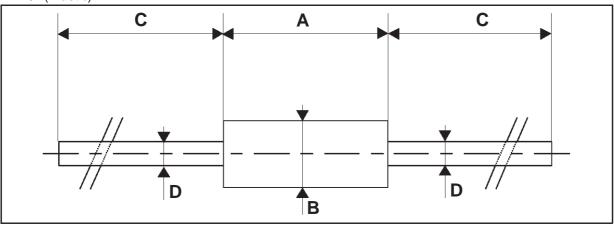
RECOVERY CHARACTERISTICS

Symbol	Т	est Conditions		Min.	Тур.	Max.	Unit
t _{rr}	$T_j = 25$ °C $V_R = 30$ V	$I_F = 1A$	$di_F/dt = -50A/\mu s$			35	ns
Qrr	T _j = 25°C V _R < 30V	I _F = 2A	$diF/dt = -20A/\mu s$		12		nC
t _{fr}	T _j = 25°C Measured at 1.1x V _F	I _F = 1A	$t_r = 10$ ns		20		ns
V _{FP}	T _j = 25°C	I _F = 1A	$t_r = 10 ns$		5		V

To evaluate the conduction losses use the following equation: $P=0.68\,x$ $I_{F(AV)}$ + $0.06\,I_{F}^{2}(_{RMS)}$

PACKAGE MECHANICAL DATA

F126 (Plastic)



	DIMENSIONS						
REF.	F. Millimeters Inch		Inches	:S			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	6.05	6.20	6.35	0.238	0.244	0.250	
В	2.95	3.00	3.05	0.116	0.118	0.120	
С	26		31	1.024		1.220	
D	0.76	0.81	0.86	0.030	0.032	0.034	

■ Marking: type number; ring at cathode end

■ Cooling method: by convection (method A)

■ Weight: 0.4 g

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